

# **isc Silicon NPN Power Transistor**

2SC4382

#### **DESCRIPTION**

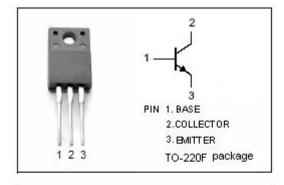
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 200V(Min)
- DC Current Gain-
  - :  $h_{FE}$ = 60(Min)@ ( $V_{CE}$ = 10V,  $I_{C}$ = 0.7A)
- Complement to Type 2SA1668
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

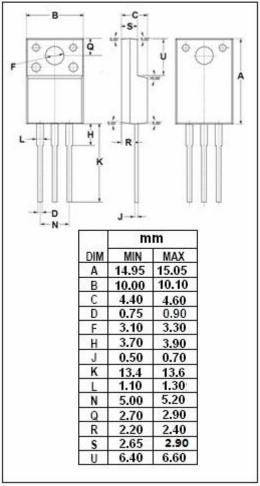
### **APPLICATIONS**

 Designed for TV vertical output ,audio output driver and general purpose applications.



SYMBOL	PARAMETER	VALUE	UNIT
V <sub>СВО</sub>	Collector-Base Voltage	200	V
Vceo	Collector-Emitter Voltage	200	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
lc	Collector Current-Continuous	2	Α
Ів	Base Current-Continuous	1	Α
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C 2		W
TJ	Junction Temperature	150	${\mathbb C}$
Tstg	Storage Temperature	-55~150	$^{\circ}\mathbb{C}$







# **ISC Silicon NPN Power Transistor**

2SC4382

#### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

1j-25 C un	ness otherwise specified								
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA ; I <sub>B</sub> = 0	200			V			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.7A; I <sub>B</sub> = 0.07A			1.0	V			
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 200V ; I <sub>E</sub> = 0			10	μ <b>А</b>			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 6V; I <sub>C</sub> = 0			10	μ <b>А</b>			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 0.7A; V <sub>CE</sub> = 10V	60						
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		35		pF			
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = -0.2A ; V <sub>CE</sub> = 12V		15		MHz			
Switching Times									
t <sub>on</sub>	Turn-On Time			1.0		μ <b>S</b>			
tstg	Storage Time	I <sub>C</sub> = 1A; I <sub>B1</sub> = -I <sub>B2</sub> = 0.1A; V <sub>CC</sub> = 20V; R <sub>L</sub> = 20 Ω		3.0		μ <b>S</b>			
t <sub>f</sub>	Fall Time			1.5		μ <b>s</b>			

### NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.